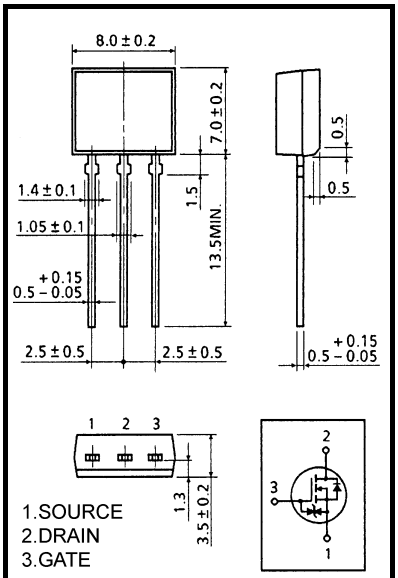
TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (π-MOSV)

# 2SK3374

Switching Regulator Applications

- Low drain-source ON-resistance: $R_{DS\ (ON)}$ = 3.7 Ω (typ.)
- High forward transfer admittance: $|Y_{fs}|$ = 0.7 S (typ.)
- Low leakage current: $I_{DSS}$ = 100 μA (max) ($V_{DS}$ = 450 V)
- Enhancement mode: $V_{th}$ = 2.0 to 4.0 V ($V_{DS}$ = 10 V, $I_D$ = 1 mA)

Unit: mm




| | |
|---|---|
| JEDEC | — |
| JEITA | — |
| TOSHIBA | 2-8M1B |

Weight: 0.54 g (typ.)

## Absolute Maximum Ratings (Ta = 25°C)

| Characteristics | | Symbol | Rating | Unit |
|---|---|---|---|---|
| Drain-source voltage | | $V_{DSS}$ | 450 | V |
| Drain-gate voltage ($R_{GS}$ = 20 kΩ) | | $V_{DGR}$ | 450 | V |
| Gate-source voltage | | $V_{GSS}$ | ±30 | V |
| Drain current | DC (Note 1) | $I_D$ | 1 | A |
| | Pulse (Note 1) | $I_{DP}$ | 2 | A |
| Drain power dissipation (Tc = 25°C) | | $P_D$ | 1.3 | W |
| Single pulse avalanche energy (Note 2) | | $E_{AS}$ | 122 | mJ |
| Avalanche current | | $I_{AR}$ | 1 | A |
| Repetitive avalanche energy (Note 3) | | $E_{AR}$ | 0.13 | mJ |
| Channel temperature | | $T_{ch}$ | 150 | °C |
| Storage temperature range | | $T_{stg}$ | −55 to150 | °C |

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook (“Handling Precautions”/“Derating Concept and Methods”) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

## Thermal Characteristics

| Characteristics | Symbol | Max | Unit |
|---|---|---|---|
| Thermal resistance, channel to ambient | $R_{th\ (ch\text{-}a)}$ | 96.1 | °C/W |

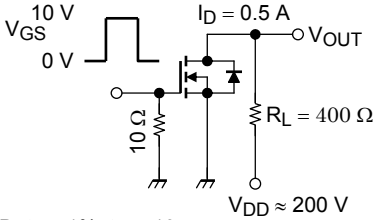
Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: $V_{DD}$ = 90 V, $T_{ch}$ = 25°C (initial), L = 203 mH, $R_G$ = 25 Ω, $I_{AR}$ = 1 A

Note 3: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic-sensitive device. Please handle with caution.

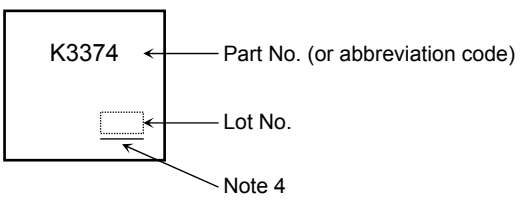
## Electrical Characteristics (Ta = 25°C)

| Characteristics | | Symbol | Test Condition | Min | Typ. | Max | Unit |
|---|---|---|---|---|---|---|---|
| Gate leakage current | | $I_{GSS}$ | $V_{GS}$ = ±25 V, $V_{DS}$ = 0 V | — | — | ±10 | μA |
| Gate-source breakdown voltage | | $V_{(BR)\ GSS}$ | $I_G$ = ±10 μA, $V_{DS}$ = 0 V | ±30 | — | — | V |
| Drain cut-off current | | $I_{DSS}$ | $V_{DS}$ = 450 V, $V_{GS}$ = 0 V | — | — | 100 | μA |
| Drain-source breakdown voltage | | $V_{(BR)\ DSS}$ | $I_D$ = 10 mA, $V_{GS}$ = 0 V | 450 | — | — | V |
| Gate threshold voltage | | $V_{th}$ | $V_{DS}$ = 10 V, $I_D$ = 1 mA | 2.0 | — | 4.0 | V |
| Drain-source ON-resistance | | $R_{DS\ (ON)}$ | $V_{GS}$ = 10 V, $I_D$ = 0.5 A | — | 3.7 | 4.6 | Ω |
| Forward transfer admittance | | $\|Y_{fs}\|$ | $V_{DS}$ = 10 V, $I_D$ = 0.5 A | 0.3 | 0.7 | — | S |
| Input capacitance | | $C_{iss}$ | $V_{DS}$ = 25 V, $V_{GS}$ = 0 V, f = 1 MHz | — | 180 | — | pF |
| Reverse transfer capacitance | | $C_{rss}$ | | — | 2 | — | |
| Output capacitance | | $C_{oss}$ | | — | 20 | — | |
| Switching time | Rise time | $t_r$ |   Duty ≤ 1%, $t_w$ = 10 μs | — | 7 | — | ns |
| | Turn-on time | $t_{on}$ | | — | 15 | — | |
| | Fall time | $t_f$ | | — | 30 | — | |
| | Turn-off time | $t_{off}$ | | — | 70 | — | |
| Total gate charge (gate-source plus gate-drain) | | $Q_g$ | $V_{DD}$ ≈ 360 V, $V_{GS}$ = 10 V, $I_D$ = 1 A | — | 5 | — | nC |
| Gate-source charge | | $Q_{gs}$ | | — | 3 | — | |
| Gate-drain (“miller”) charge | | $Q_{gd}$ | | — | 2 | — | |

## Source-Drain Ratings and Characteristics (Ta = 25°C)

| Characteristics | Symbol | Test Condition | Min | Typ. | Max | Unit |
|---|---|---|---|---|---|---|
| Continuous drain reverse current (Note 1) | $I_{DR}$ | — | — | — | 1 | A |
| Pulse drain reverse current (Note 1) | $I_{DRP}$ | — | — | — | 2 | A |
| Forward voltage (diode) | $V_{DSF}$ | $I_{DR}$ = 1 A, $V_{GS}$ = 0 V | — | — | −1.7 | V |
| Reverse recovery time | $t_{rr}$ | $I_{DR}$ = 1 A, $V_{GS}$ = 0 V, $dI_{DR}/dt$ = 100 A/μs | — | 350 | — | ns |
| Reverse recovery charge | $Q_{rr}$ | | — | 1.3 | — | μC |

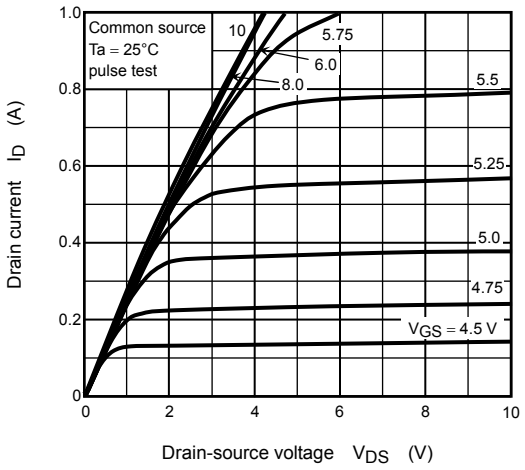
## Marking



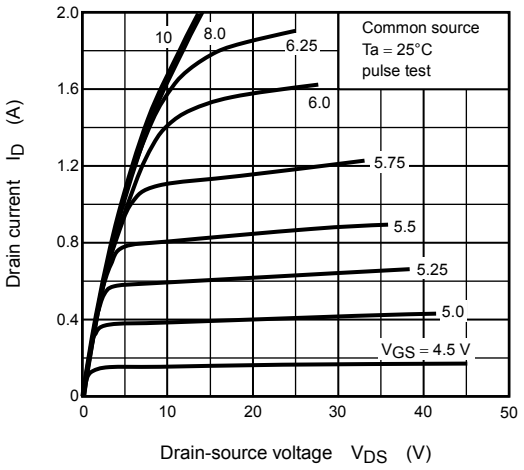

Note 4: A line under a Lot No. identifies the indication of product Labels.
Not underlined: [[Pb]]/INCLUDES > MCV
Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is the Directive 2002/95/EC of the European Parliament and of the Council of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

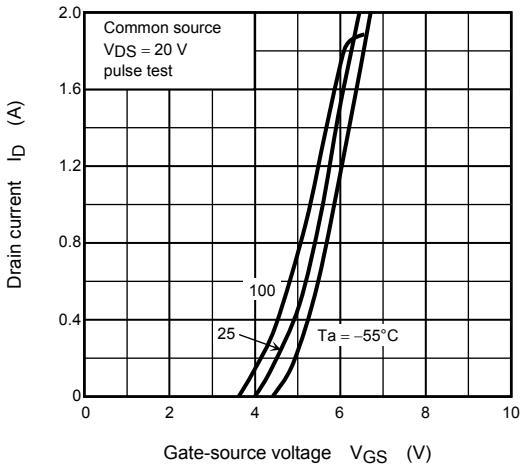
$I_D - V_{DS}$



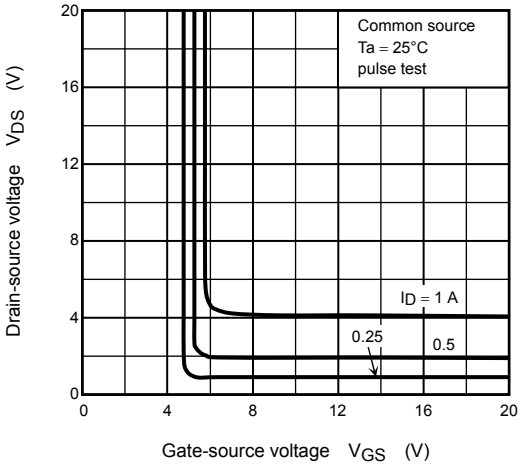

$I_D - V_{DS}$



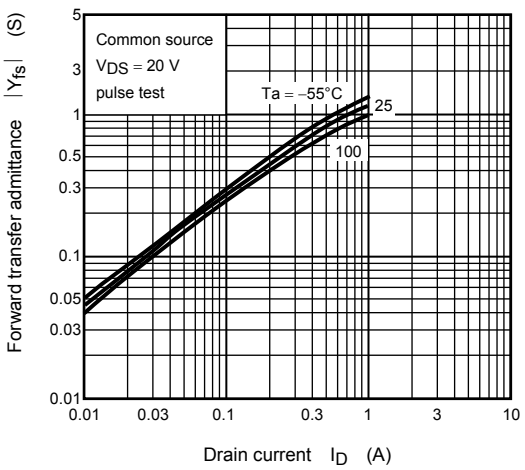

$I_D - V_{GS}$



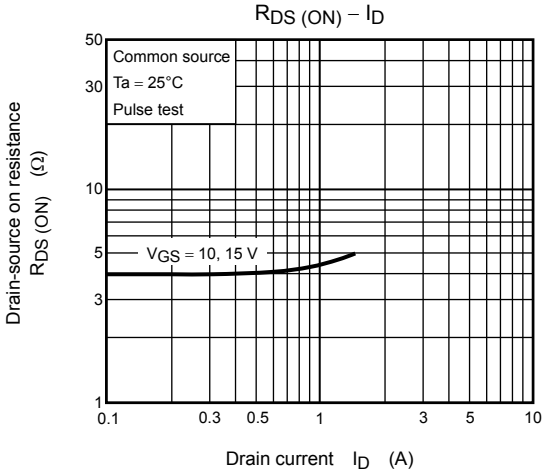

$V_{DS} - V_{GS}$



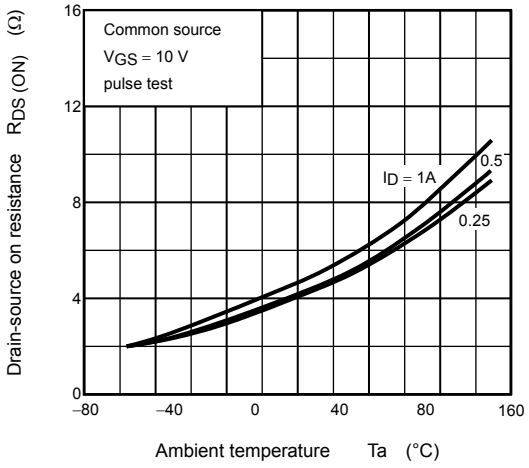

$|Y_{fs}| - I_D$



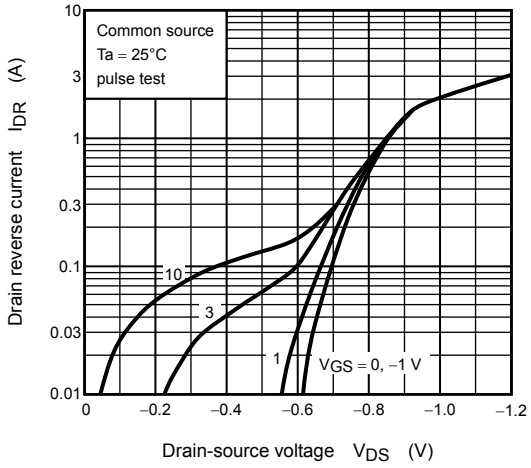

$R_{DS\ (ON)} - I_D$



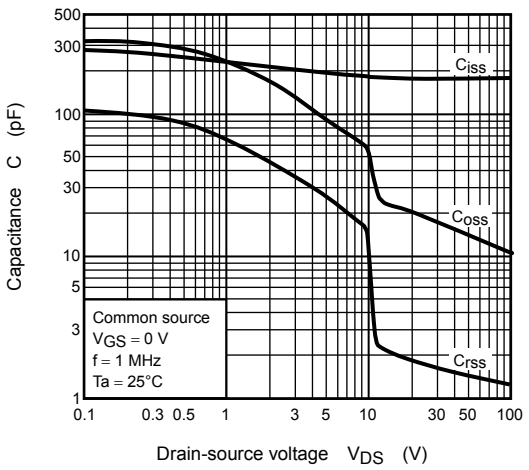
$R_{DS\ (ON)}$ – Ta



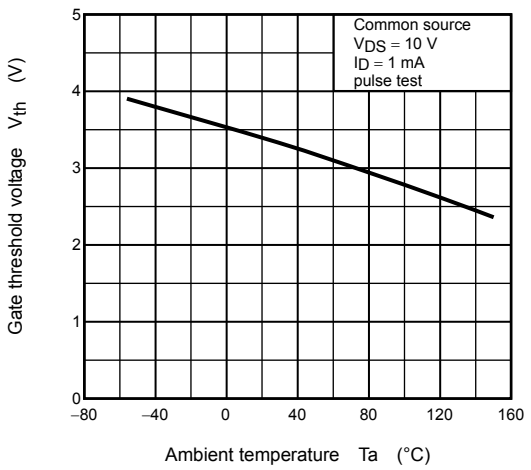

$I_{DR}$ – $V_{DS}$



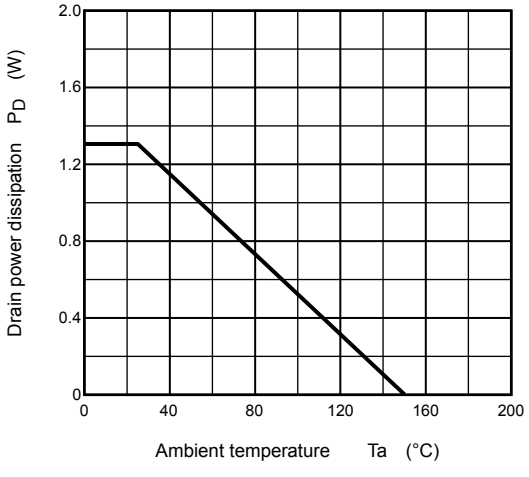

Capacitance – $V_{DS}$



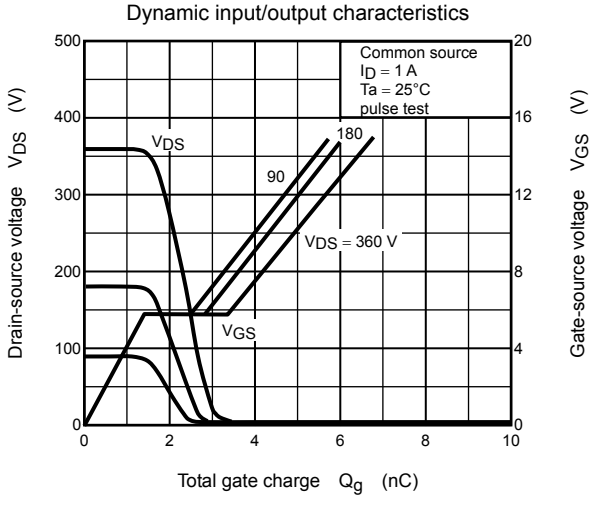

$V_{th}$ – Ta



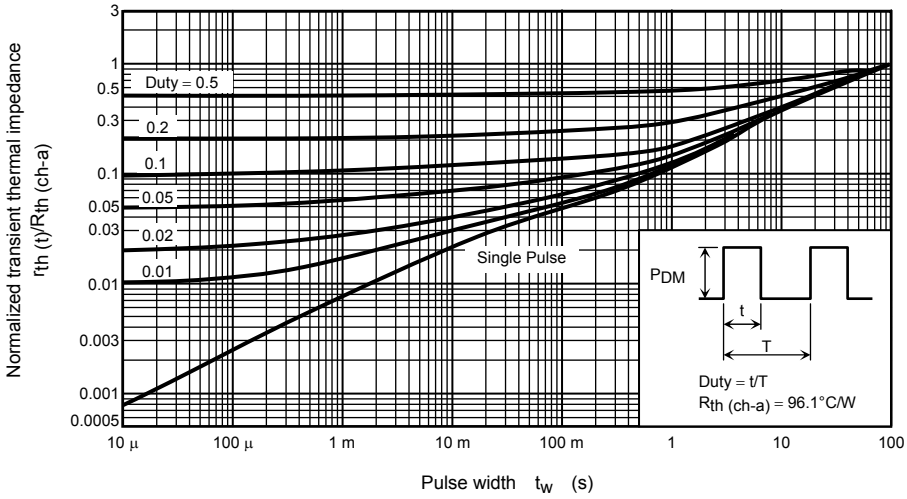

$P_D$ – Ta



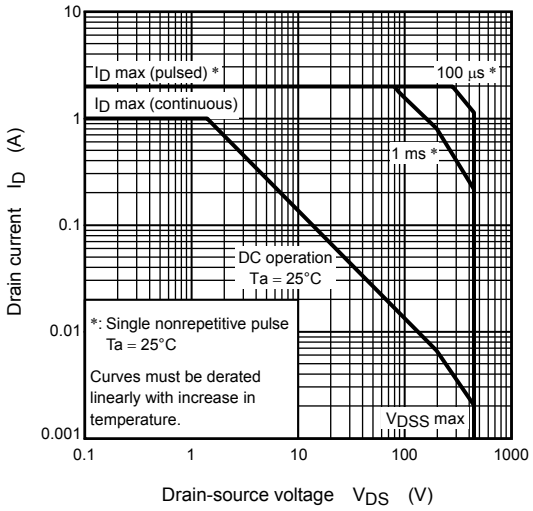

Dynamic input/output characteristics



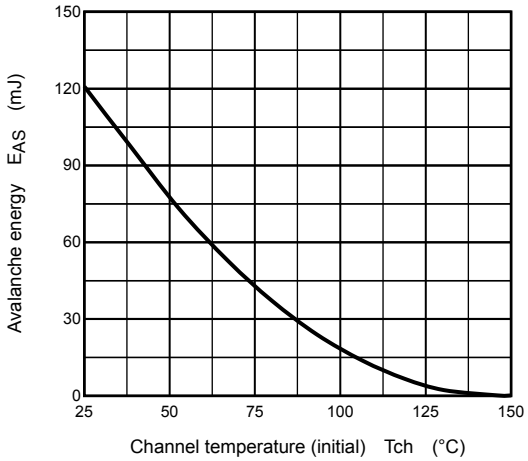
$r_{th} - t_w$

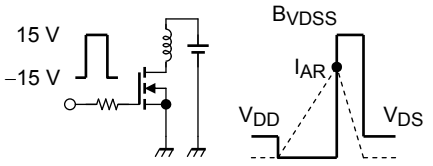



Safe operating area




$E_{AS} - T_{ch}$




Test circuit Waveform

$R_G = 25\ \Omega$
$V_{DD} = 90$ V, L = 203 mH

$$E_{AS} = \frac{1}{2} \cdot L \cdot I^2 \cdot \left( \frac{B_{VDSS}}{B_{VDSS} - V_{DD}} \right)$$

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